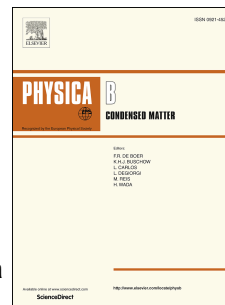


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Electron – Phonon interaction to tune metal – Semiconductor junction characteristics:
Ultralow potential barrier and less non-thermionic emission

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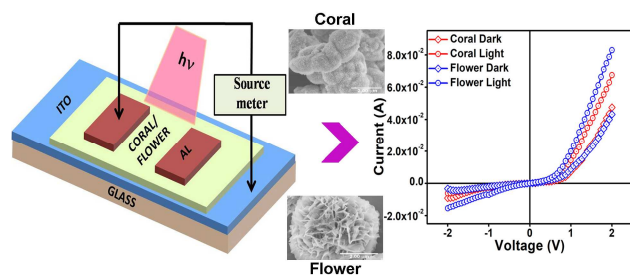
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